

2024.10

Thin Film Chip Resistors [ERA_V/K/P series]

High stability and reliability type

Contributing to higher precision and longer service life of industrial, infrastructure, and in-vehicle equipment.

Product summary

■ Achieves higher stability and reliability with new material and construction.

Features

- High precision : Tolerance ±0.05%, Temperature coefficient of resistance ±10 x10⁻⁶/K
- High durability : ESD, overload, thermal shock
- Highly corrosive: Sulfurized environment, high humidity environment, etc.
- Suppression of solder cracks with stress relaxation structure
- Current concentration relaxation pattern design to increase ESD voltage immunity
- Corrosion resistance achieved through electrode material selection and original construction method

Structure-1

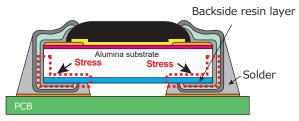
Unique structural design achieves High precision and High durability

☐ Resistance tolerance : ±0.05 %

☐ TCR : **±10** x10⁻⁶/K

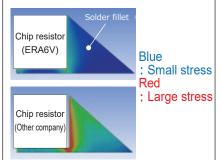
 \square High reliability $\triangle R$: Equivalent to or better than conventional products

 Achieve excellent anti solder joint cracking by back side resin layer





Applied distribution simulation (stress at 155 $^{\circ}\text{C}$ with 25 $^{\circ}\text{C}$ as the reference)

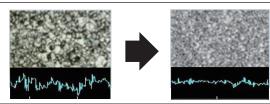


Unique stress-relieving structure

② Improved element & patterning, current concentration relief

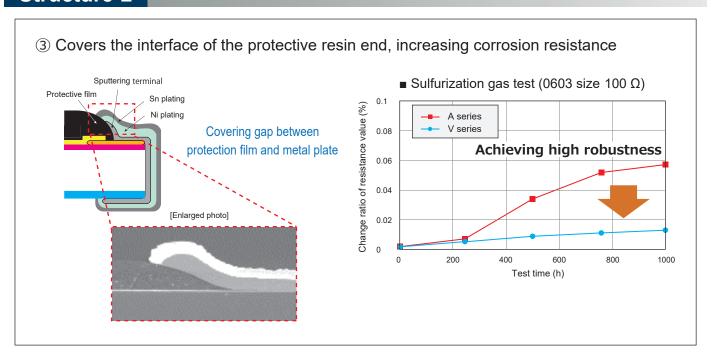
This grain structure and unique pattern design reduce load concentration in the event of overload

Reference : Surface roughness of alumina substrate



Isuue: Panasonic Industry Co., Ltd. Device Solutions Business Division 1006 Kadoma, Kadoma City, Osaka, 571-8506 Japan

Structure-2



Applications

· Voltage (voltage division) detection : BMS, inverters, OBC, DC/DC converters, etc.

Amplifier gain control
LiDAR, sensing, etc.

Product line up

Size (Rated vol.)	Part No.	TCR (×10 ⁻⁶ /K)	Resistance range (Ω)		Limiting element	ESD resistance	Category temp.
			±0.05 % (W)*1	±0.1 % (B)*1	voltage (V)	AEC-Q200	range (℃)
0402 (0.1 W)*1	ERA2V	±10(R)	1k≦F	R≦47k		1.0 kV (class 1C)	
		±15(P)	_	1k≦R≦47k	75 ^{*1}		
		±25(E)	_	47≦R≦100k			
0603 (0.125 W)*1	ERA3V ERA3K(Over 100Ω)	±10(R)	1k≦R	≦100k		1.5 kV (class 1C)	
		±15(P)	_	1k≦R≦100k	100⁴		
		±25(E)	_	47≦R≦240k			
0805 (0.25 W)*1	ERA6V ERA6K(Over 100Ω)	±10(R)	1k≦R≦100k				-55 to +155
		±15(P)	_	1k≦R≦100k	150⁴	2.0 kV (class 2)	
		±25(E)	_	47≦R≦750k			
1206 (0.25 W)	ERA8V ERA8K(Over 100Ω)	±10(R)	1k≦R≦160k				
		±15(P)	_	1k≦R≦1M	200°1	2.0 kV (class 2)	
		±25(E)	_	47≦R≦1M			
	ERA8P	±15(P)	_	160≦R≦1M	- 500°²	4.0 kV*² (class 3)	
		±25(E)	_	160≦R≦1M			

^{*1 :} Comparison of performance with conventional products - Can be reduced by 1 size

[ERA-V]



[ERA-P]

^{*2 :} New lineup of high voltage products